



N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
30	0.009 at V _{GS} = 10 V	11		
	0.010 at V _{GS} = 4.5 V	10		
	0.014 at V _{GS} = 2.5 V	8.8		

FEATURES

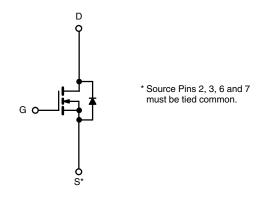
- · Halogen-free
- TrenchFET® Power MOSFETS: 2.5 V Rated
- 30 V V_{DS}

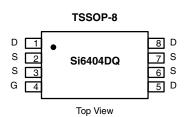


RoHS COMPLIANT

APPLICATIONS

- Battery Switch
- · Charger Switch





Ordering Information: Si6404DQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V	
Gate-Source Voltage		V_{GS}	± 12			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	11	8.6	٨	
	T _A = 70 °C		8.9	6.9		
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	30		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	1.5	1.5 0.95		
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	1.75	1.08	W	
	T _A = 70 °C		1.14	0.69	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipular Landian to Auditoria	t ≤ 10 s	- R _{thJA}	55	70	°C/W
Maximum Junction-to-Ambient ^a	Steady State		95	115	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	35	45]

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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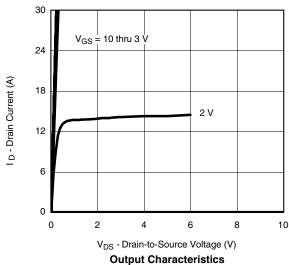


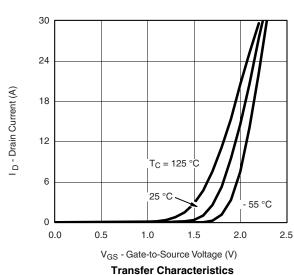
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.6			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA	
Zero Gate Voltage Drain Current	lass	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1		
	I _{DSS}	V_{DS} = 24 V, V_{GS} = 0 V, T_J = 70 °C			10	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	20			Α	
Drain-Source On-State Resistance ^a		V _{GS} = 10 V, I _D = 11 A		0.0073	0.009	Ω	
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$		0.0084	0.010		
		$V_{GS} = 2.5 \text{ V}, I_D = 8.8 \text{ A}$		0.0116	0.014		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 11 A		27		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.5 A, V _{GS} = 0 V		0.72	1.1	V	
Dynamic ^b				•			
Total Gate Charge	Qg			32	48		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 11 \text{ A}$		8.1		nC	
Gate-Drain Charge	Q_{gd}			10			
Gate Resistance	R_g			7.5		Ω	
Turn-On Delay Time	t _{d(on)}			35	55		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		35	55	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 4.5 V, R_G = 6 Ω		100	150		
Fall Time	t _f			50	75		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 1.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		40	85		

Notes: a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

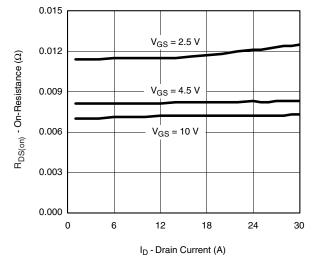
TYPICAL CHARACTERISTICS 25 °C unless noted



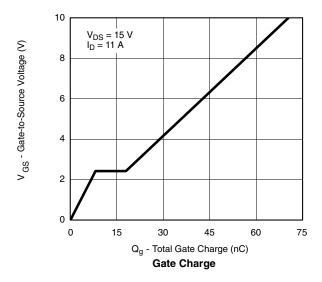


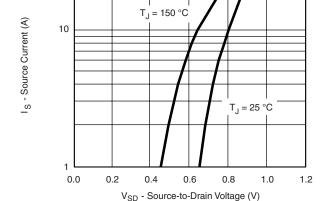


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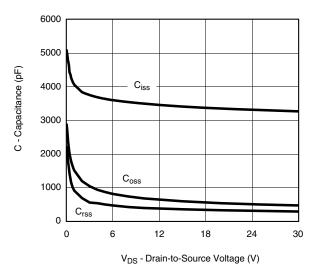


On-Resistance vs. Drain Current

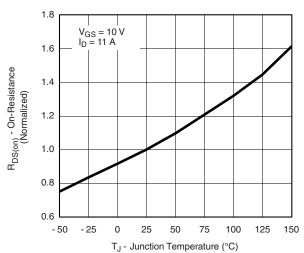




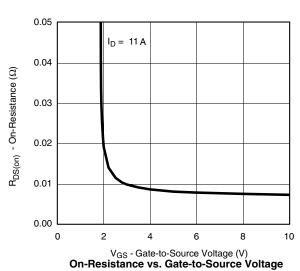
Source-Drain Diode Forward Voltage







On-Resistance vs. Junction Temperature

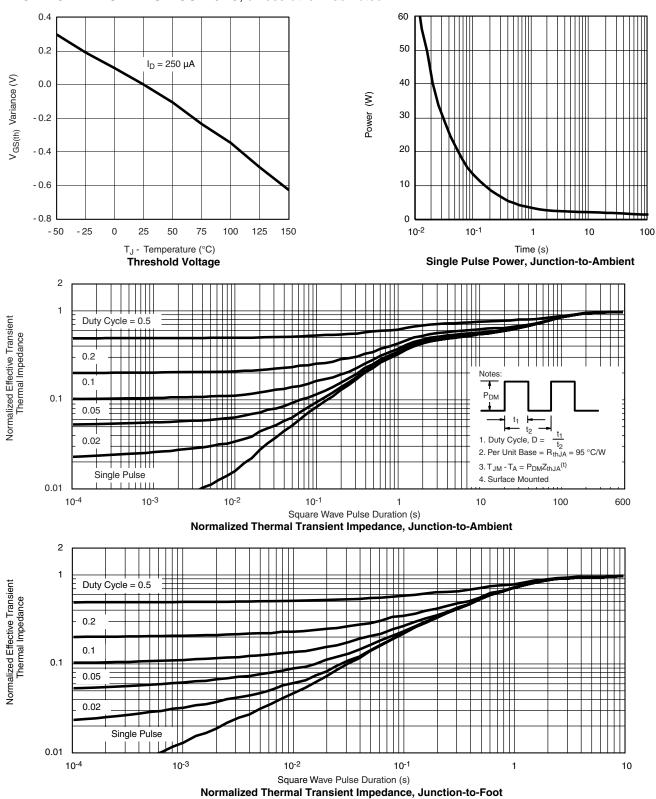


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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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